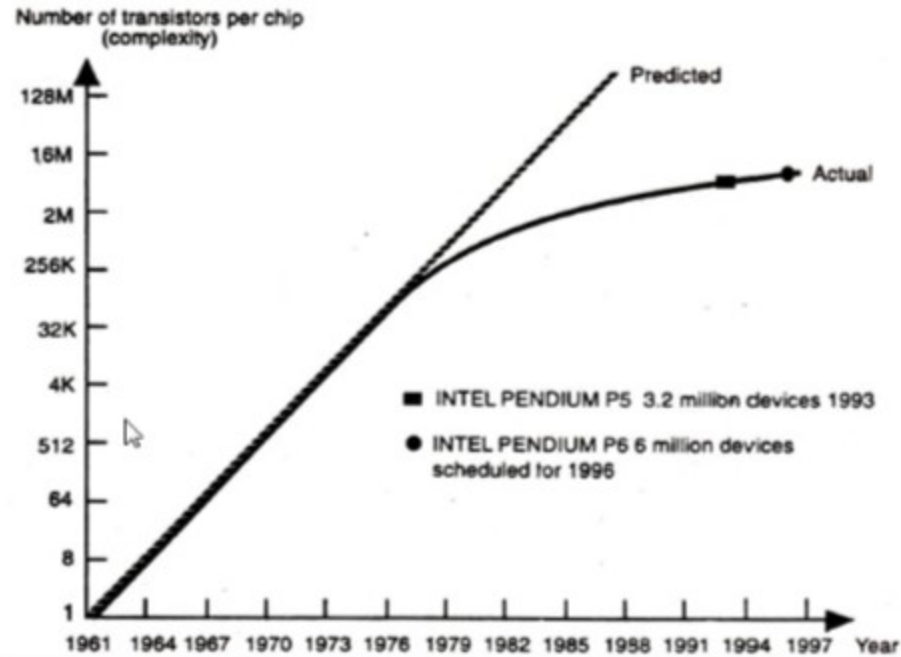


INTRODUCTION TO INTEGRATED CIRCUIT TECHNOLOGY



Note: K signifies a multiplier of 1024 and M a multiplier of 1,048,576.

METAL-OXIDE-SEMICONDUCTOR (MOS) AND RELATED VLSI TECHNOLOGY

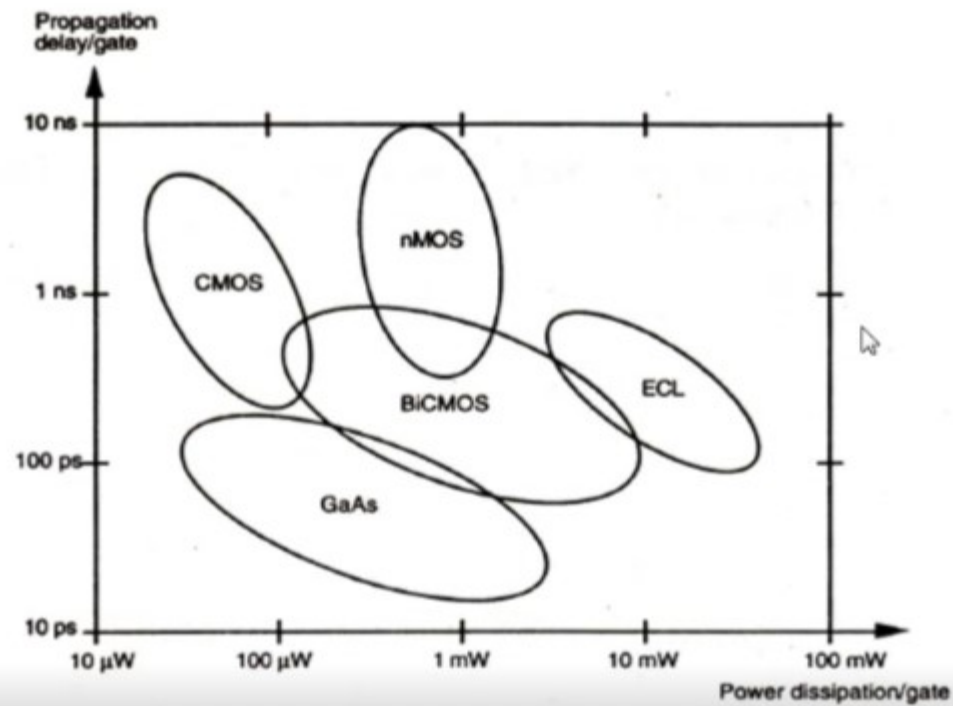
TABLE 1.1 Microelectronics evolution

Year	1947	1950	1961	1966	1971	1980	1990	2000
Technology	Invention of the transistor	Discrete components	SSI	MSI	LSI	VLSI	ULSI*	GSI†
Approximate numbers of transistors per chip in commercial products	1	1	10	100–1000	1000–20,000	20,000–1,000,000	1,000,000–10,000,000	>10,000,000
Typical products	—	Junction Transistor and diode	Planar devices Logic gates Flip-flops	Counters Multiplexers Adders	8 bit micro-processors ROM RAM	16 and 32 bit micro-processors Sophisticated peripherals GHM Dram	Special processors, Virtual reality machines, smart sensors	

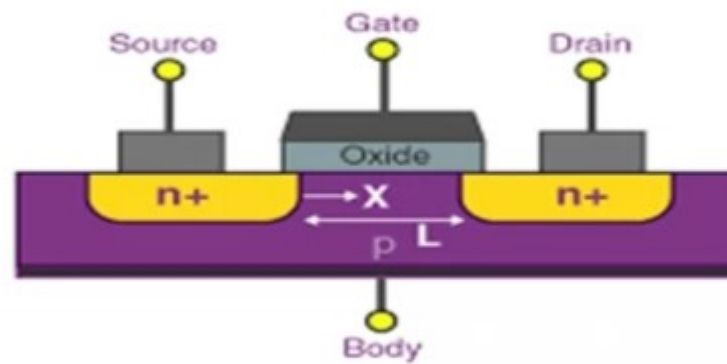
* Ultra large-scale integration

† Giant-scale integration

DIFFERENT FABRICATION TECHNOLOGIES

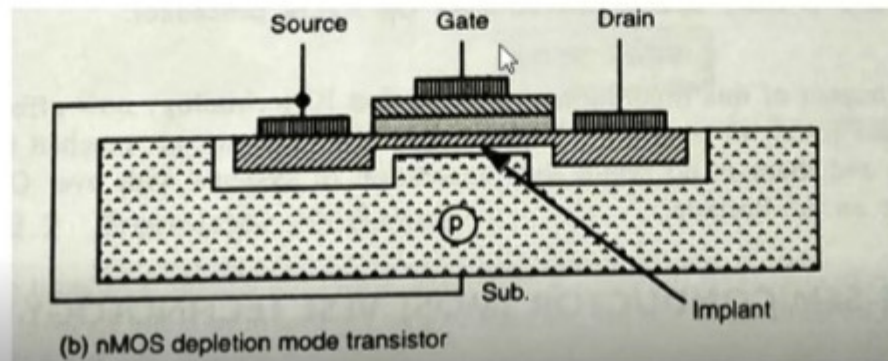
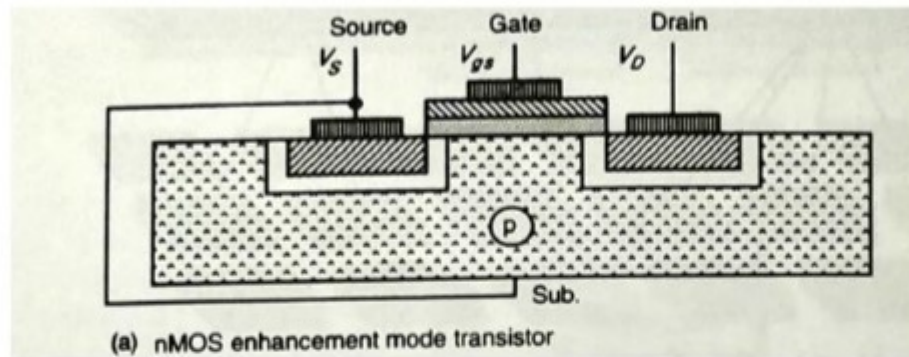


MOSFET



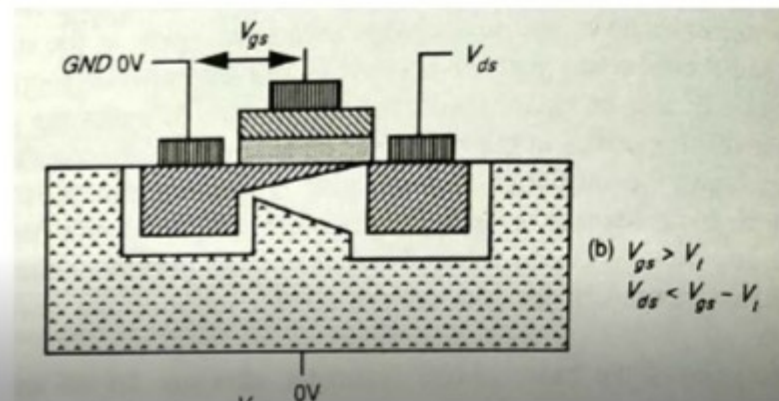
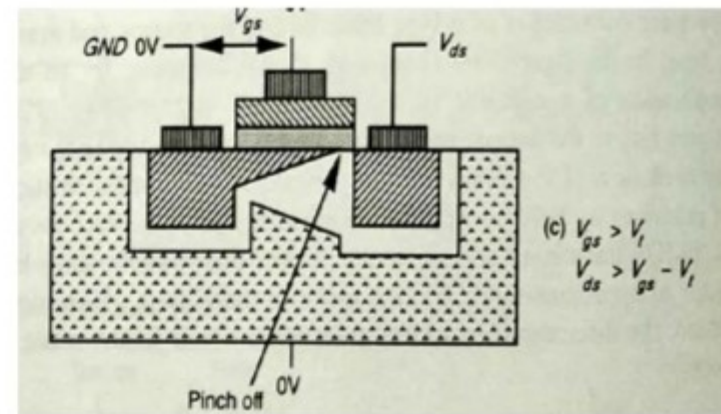
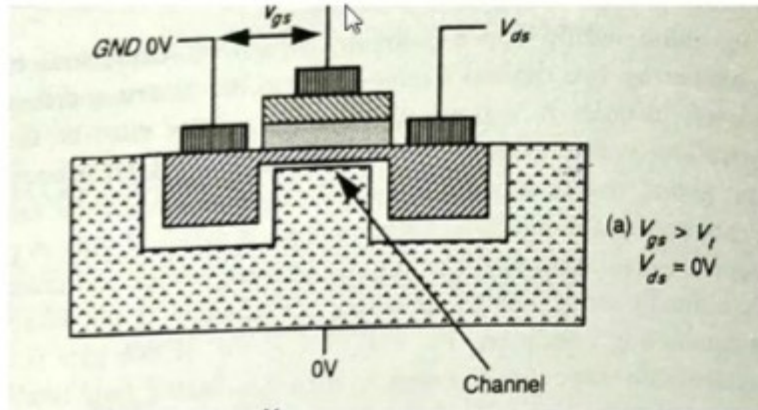
Fundamentals of MOSFET

Basic MOS Transistor



KEY	
	Metal
	Polysilicon
	Oxide
	n-diffusion
	p-diffusion
	p-substrate
	n-substrate
	Depletion

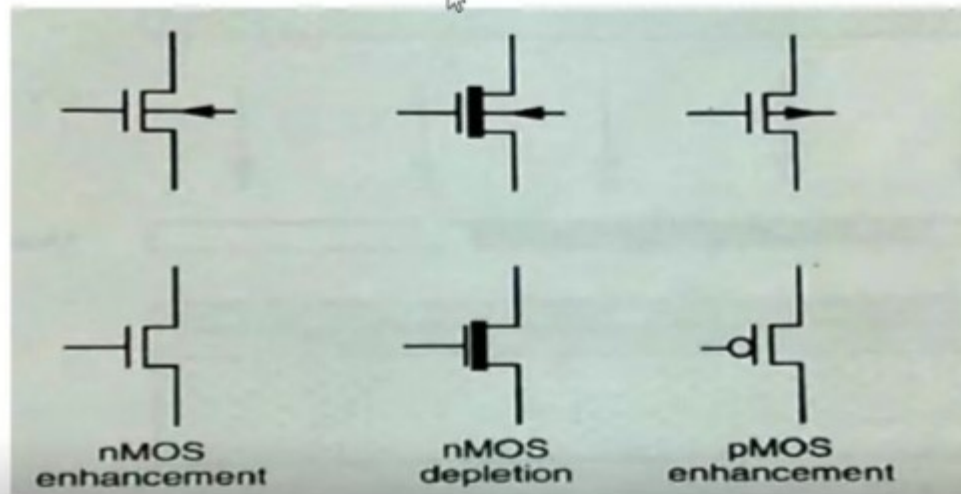
Enhancement mode Transistor



Enhancement mode transistor for particular values V_{ds} with $(V_{gs} > V_t)$

Depletion Mode Transistor

- The channel is established because of the implant even when $V_{gs}=0$ and
- To cause the channel to cease to exist a negative voltage V_{td} must be applied between gate and source
- $V_{td} < -0.8V_{DD}$



Transistor Circuit Symbols